

# BLS6G2933P-200

LDMOS S-Band radar pallet amplifier

Rev. 01 — 28 May 2010

Objective data sheet

## 1. Product profile

### 1.1 General description

200 W LDMOS amplifier pallet intended for radar applications in the 2.9 GHz to 3.3 GHz range.

**Table 1. Typical performance**

RF performance at  $T_{case} = 25\text{ °C}$  in a common source class-AB test circuit.

Mode of operation	f (GHz)	V <sub>DS</sub> (V)	P <sub>L(1dB)</sub> (W)	G <sub>p</sub> (dB)	η <sub>D</sub> (%)	I <sub>Dq</sub> (mA)
class-AB; t <sub>p</sub> = 300 μs; δ = 10 %	2.9 to 3.3	32	220	11	45	100

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

### 1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- Excellent thermal stability
- Designed for broadband operation (2.9 GHz to 3.3 GHz)
- Matched to 50 Ω for ease of use
- Extreme low weight pallet (environmental friendly and easy to use)

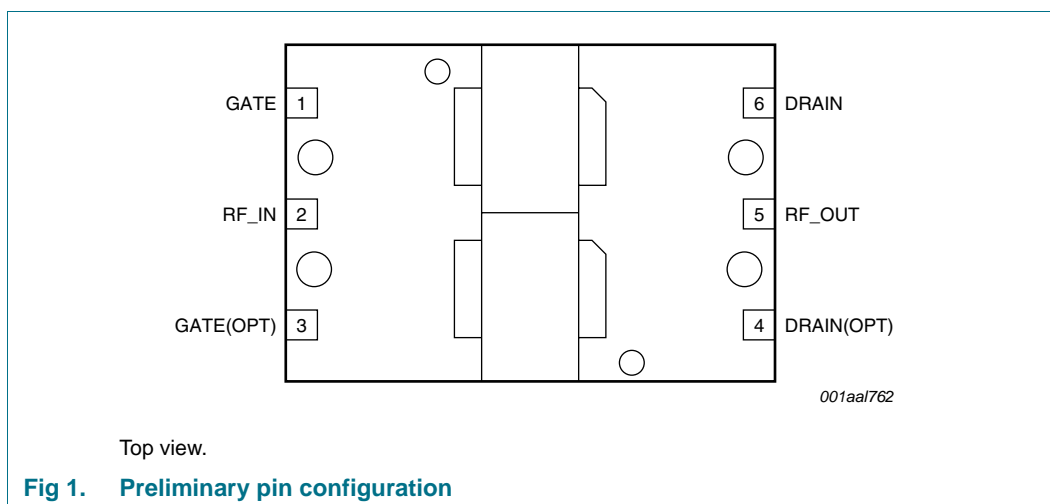
### 1.3 Applications

- General S-Band radar applications



## 2. Pinning information

### 2.1 Pinning



### 2.2 Pin description

**Table 2. Pin description**<sup>[1]</sup>

Symbol	Pin	Description
GATE	1	gate
RF_IN	2	RF input
GATE(OPT)	3	optional gate
DRAIN(OPT)	4	optional drain
RF_OUT	5	RF output
DRAIN	6	drain

[1] The case is a source/ground connection.

## 3. Ordering information

**Table 3. Ordering information**

Type number	Package		Version
	Name	Description	
BLS6G2933P-200	-	<td>	<td>

## 4. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	60	V
$V_{GS}$	gate-source voltage		-	$\pm 11$	V
$I_D$	drain current		-	66	A
$T_{stg}$	storage temperature		-40	+125	$^{\circ}\text{C}$
$T_j$	junction temperature		-	200	$^{\circ}\text{C}$

## 5. Thermal characteristics

**Table 5. Thermal characteristics**

Symbol	Parameter	Conditions	Typ	Unit
$Z_{th(j-h)}$	transient thermal impedance from junction to heatsink	$T_h = 25\text{ }^{\circ}\text{C}; P_L = 200\text{ W}$		
		$t_p = 300\text{ }\mu\text{s}; \delta = 10\text{ }\%$	[1] <td>	K/W
		$t_p = 200\text{ }\mu\text{s}; \delta = 10\text{ }\%$	[1] <td>	K/W
		$t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$	[1] <td>	K/W

[1] Measured from junction to heatsink of the pallet.

## 6. Characteristics

**Table 6. Characteristics per section**

$T_j = 25\text{ }^{\circ}\text{C}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 1\text{ mA}$	60	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 360\text{ mA}$	1.4	1.8	2.3	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 28\text{ V}$	-	-	10	$\mu\text{A}$
$I_{GSS}$	gate leakage current	$V_{GS} = \pm 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	900	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 10\text{ A}$	-	13	-	S

## 7. Application information

**Table 7. Application information**

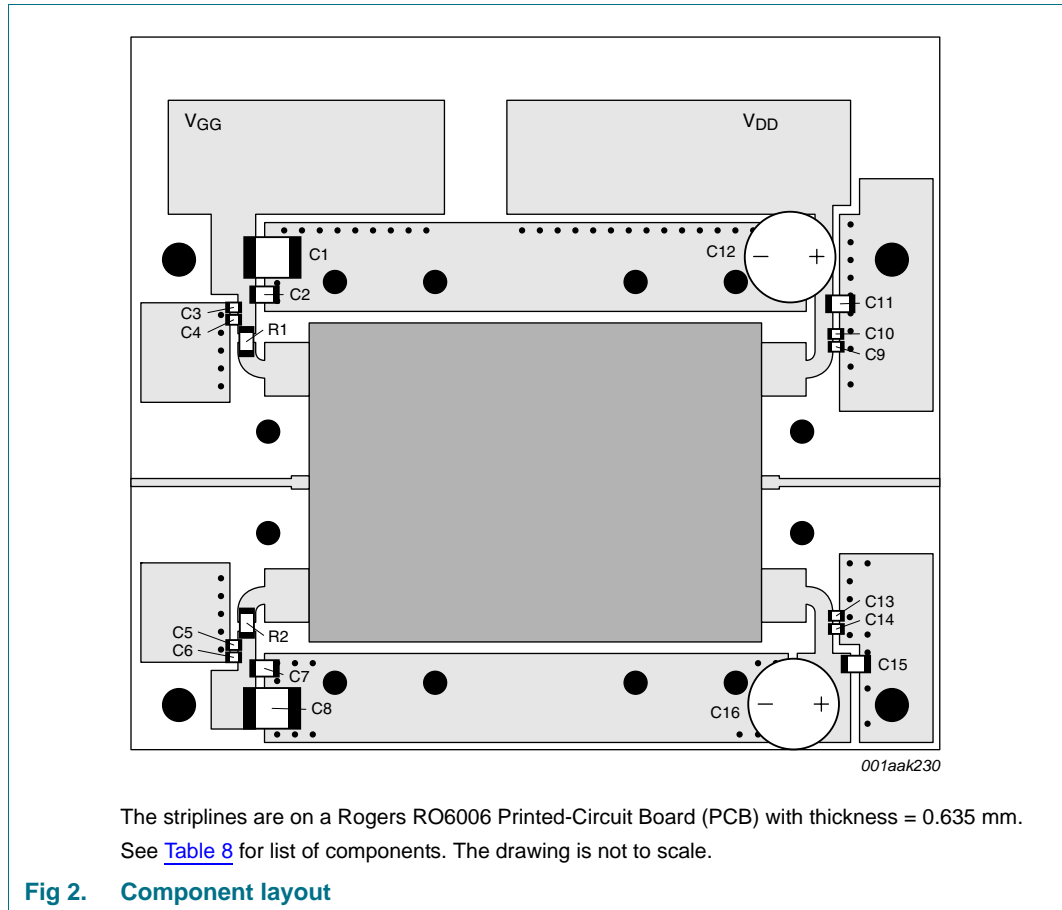
*RF performance in common source class-AB circuit;  $T_h = 25\text{ °C}$ ;  $t_p = 300\text{ }\mu\text{s}$ ;  $\delta = 10\%$ ;  $I_{Dq} = 100\text{ mA}$ ;  $P_L = 215\text{ W}$ ;  $Z_{th} = <td> K/W$ ; unless otherwise specified.*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f	frequency		2.9	-	3.3	GHz
V <sub>CC</sub>	supply voltage		-	-	32	V
t <sub>p</sub>	pulse duration		-	-	300	$\mu\text{s}$
$\delta$	duty cycle		-	10	-	%
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		-	220	-	W
G <sub>p</sub>	power gain		10	11	-	dB
$\eta_D$	drain efficiency		40	45	-	%
P <sub>droop(pulse)</sub>	pulse droop power		-	0.1	0.3	dB
Z <sub>i</sub>	input impedance		-	50	-	$\Omega$
Z <sub>o</sub>	output impedance		-	50	-	$\Omega$
IRL	input return loss		-	-10	-	dB

### 7.1 Ruggedness in class-AB operation

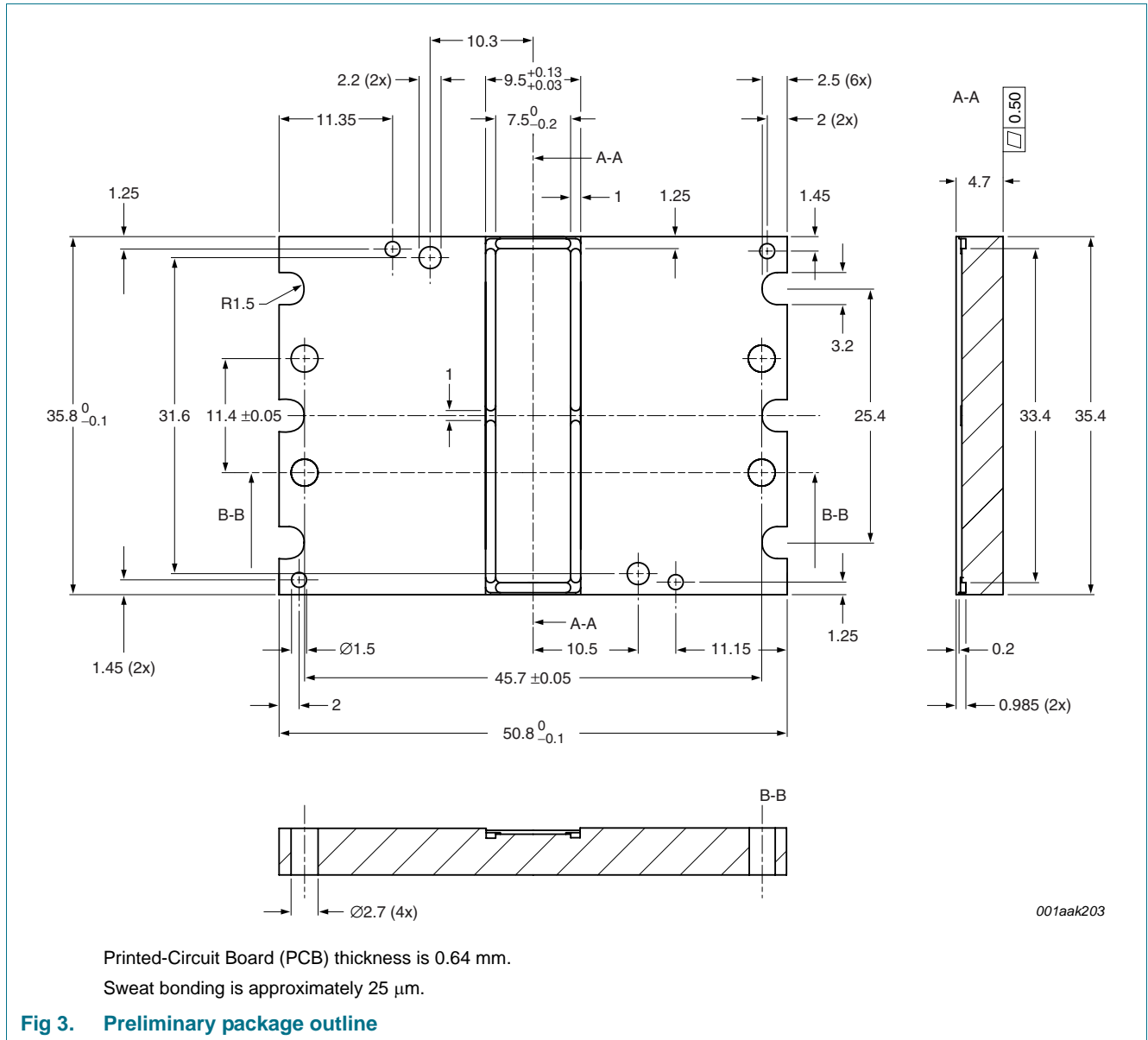
The BLS6G2933P-200 is capable of withstanding a load mismatch corresponding to VSWR = 5 : 1 through all phases under the following conditions: V<sub>DS</sub> = 32 V; I<sub>Dq</sub> = 100 mA; P<sub>L</sub> = 215 W pulsed; t<sub>p</sub> = 300  $\mu\text{s}$ ;  $\delta = 10\%$ .

## 8. Test information

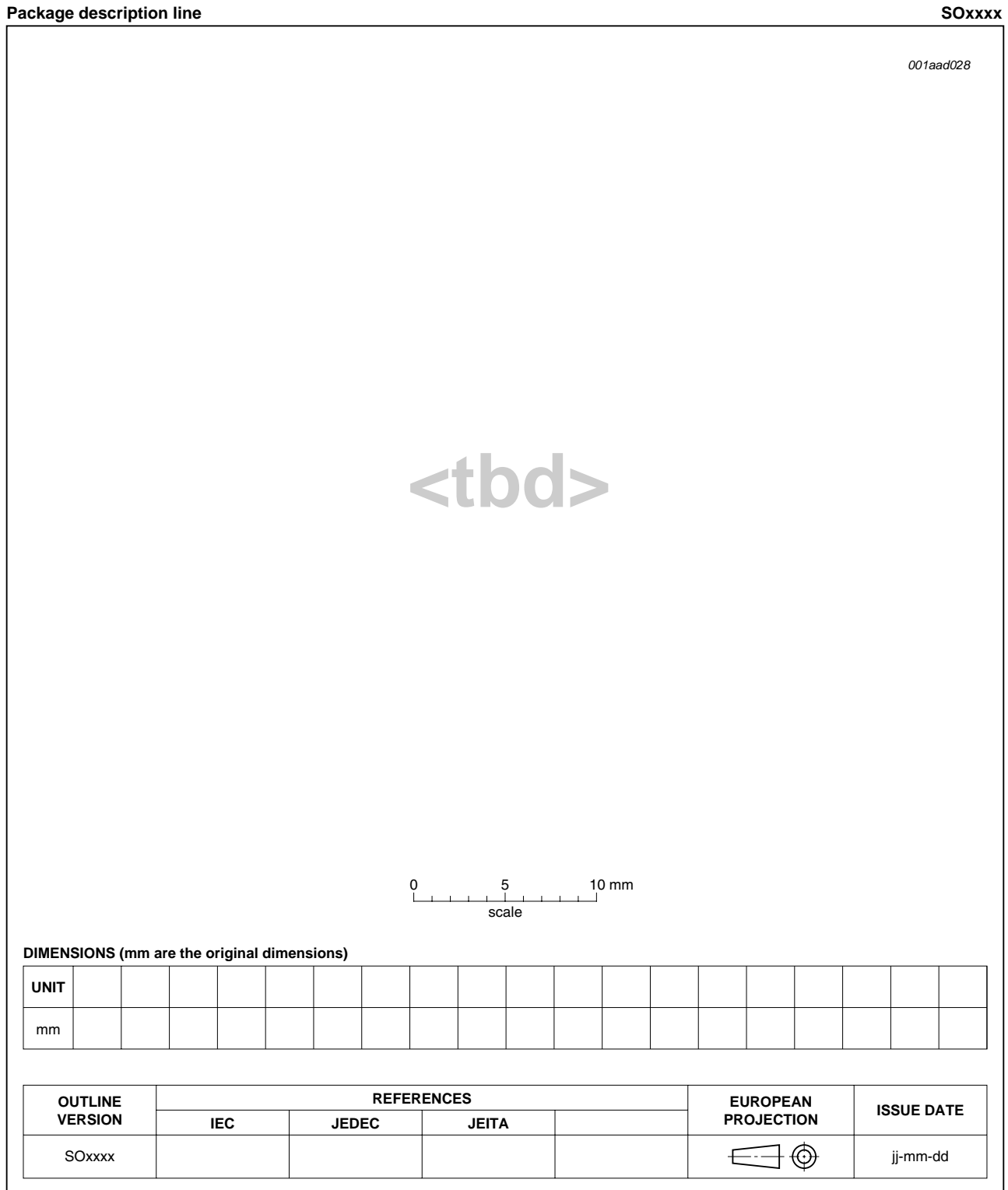
**Table 8. List of components**See [Figure 2](#) for component layout.

Component	Description	Value	Remarks
C1, C8	multilayer ceramic chip capacitor	47 $\mu$ F	TDK
C2, C7, C11, C15	multilayer ceramic chip capacitor	100 pF	ATC100B
C3, C4, C5, C6, C9, C10, C13, C14	multilayer ceramic chip capacitor	33 pF	ATC100A
C12	electrolytic capacitor	680 $\mu$ F	
C16	electrolytic capacitor	68 $\mu$ F	
R1, R2	SMD resistor	33 $\Omega$	thin film

**9. Package information**



**10. Package outline**



**Fig 4. Package outline**

## 11. Abbreviations

**Table 9. Abbreviations**

Acronym	Description
LDMOS	Laterally Diffused Metal Oxide Semiconductor
RF	Radio Frequency
S-Band	Short wave Band
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio

## 12. Revision history

**Table 10. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS6G2933P-200 v.1	20100528	Objective data sheet	-	-



## 13. Legal information

### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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